



012004

13281 U.S. PTO

Case Docket Number: 50432-395

Customer Number: 20277

UTILITY PATENT APPLICATION
UNDER 37 CFR 1.53(b)22553 U.S. PTO
10/759171

012004

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450
Sir:

Transmitted herewith for filing is the patent application of:

INVENTOR: Akif SULTAN, Qi XIANG, Bin YU
FOR: METHOD OF FORMING MINIATURIZED POLYCRYSTALLINE SILICON
GATE ELECTRODES USING SELECTIVE OXIDATION

Enclosed are:

- ☒ 8 pages of specification, claims, abstract.
- ☒ Declaration and Power of Attorney.
- ☐ Priority Claimed.
- ☐ Certified copy of _____
- ☒ 8 sheets of formal drawing.
- ☒ An assignment of the invention to ADVANCED MICRO DEVICES, INC.
and the assignment recordation fee.
- ☐ An associate power of attorney.
- ☐ A verified statement to establish small entity status under 37 CFR 1.9 and 37 CFR 1.27.
- ☐ Information Disclosure Statement, Form PTO-1449 and reference.
- ☒ Return Receipt Postcard
- ☒ Non-Publication Notice

The filing fee has been calculated as shown below:

| | NO. OF CLAIMS | | EXTRA CLAIMS | RATE | AMOUNT |
|-----------------------------|------------------|-----|-----------------|---------|----------|
| Total Claims | 15 | -20 | 0 | \$18.00 | \$0.00 |
| Independent Claims | 1 | -3 | 0 | \$86.00 | \$0.00 |
| Multiple Dependent Claim(s) | | | | | \$0.00 |
| Basic Fee | | | | | \$770.00 |
| Total of Above Calculations | | | | | \$770.00 |
| Less 1/2 for Small Entity | | | | | \$0.00 |
| Assignment & Recording Fee | | | | | \$40.00 |
| Total Fee | | | | | \$810.00 |

- ☒ Please charge my Deposit Account No. 500417 in the amount of \$810.00. A duplicate copy of this sheet is enclosed.
- ☒ The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 500417. A duplicate copy is enclosed.
- ☒ Any additional filing fees required under 37 CFR 1.16.
- ☒ The Commissioner is hereby authorized to charge payment of the following fees during the pendency of this application or credit any overpayment to Deposit Account No. 500417. A duplicate copy of this sheet is enclosed.
- ☒ Any patent application processing fees under 37 CFR 1.17.
- ☒ Any filing fees under 37 CFR 1.16 for presentation of extra claims.

Respectfully submitted,

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| | | | |
|--|----------------------|---|----------------------------|
| REQUEST AND CERTIFICATION UNDER 35 U.S.C. 122(b)(2)(B)(i) | First Named Inventor | | Akif SULTAN, et al. |
| | Title | METHOD OF FORMING MINIATURIZED POLYCRYSTALLINE SILICON GATE ELECTRODES USING SELECTIVE OXIDATION | |
| | Atty Docket Number | | 50432-395 |

I hereby certify that the invention disclosed in the attached application **has not and will not be** the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing. I hereby request that the attached application not be published under 35 U.S.C. 122(b).

Date

Signature

01/20/2004

Arthur J. Steiner, 26,106

Typed or printed name

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing**.

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant **must** notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. **Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).**